



安徽富信半导体科技有限公司

ANHUI FOSAN SEMICONDUCTOR TECHNOLOGY CO., LTD.

SOT-23 数字晶体管(SOT-23 Digital Transistors)

产品型号 Type	极性 Polarity	V _{CC}	I _O	P _D	fT	I _f (mA)	G(min)	R1	R2	印字 Marking
		V	mA	mW	MHz	@Vin5V	@5V5mA	KΩ	KΩ	
DTA113T	PNP	-50	-100	200	250	-3.8	100	1	∞	91
DTA113Z	PNP	-50	-100	200	250	-7.2	33	1	10	11
DTA114E	PNP	-50	-100	200	250	-0.88	30	10	10	14
DTA114G	PNP	-50	-100	200	250	-7.2	30	0	10	K14
DTA114T	PNP	-50	-100	200	250	-0.88	100	10	∞	94
DTA114W	PNP	-50	-100	200	250	-0.88	24	10	4.7	74
DTA114Y	PNP	-50	-100	200	250	-0.88	68	10	47	54
DTA115E	PNP	-50	-100	200	250	-0.15	82	100	100	19
DTA115G	PNP	-50	-100	200	250	-0.88	82	0	100	K19
DTA115T	PNP	-50	-100	200	250	-0.15	100	100	∞	99
DTA115U	PNP	-50	-100	200	250	-0.1	27	100	10	79
DTA123E	PNP	-50	-100	200	250	-3.8	20	2.2	2.2	12
DTA123J	PNP	-50	-100	200	250	-3.8	60	2.2	47	32
DTA123Y	PNP	-50	-100	200	250	-3.8	33	2.2	10	52
DTA124E	PNP	-50	-100	200	250	-0.38	56	22	22	15
DTA124G	PNP	-50	-100	200	250	-0.88	56	0	10	K15
DTA124T	PNP	-50	-100	200	250	-1.8	100	22	∞	95
DTA124X	PNP	-50	-100	200	250	-0.38	68	22	47	35
DTA125T	PNP	-50	-100	200	250	-0.33	100	200	∞	9A
DTA143E	PNP	-50	-100	200	250	-1.8	20	4.7	4.7	13
DTA143T	PNP	-50	-100	200	250	-7.2	100	4.7	∞	93
DTA143X	PNP	-50	-100	200	250	-1.8	30	4.7	10	33
DTA143Y	PNP	-50	-100	200	250	-1.8	56	4.7	22	53
DTA143Z	PNP	-50	-100	200	250	-1.8	60	4.7	47	E13
DTA144E	PNP	-50	-100	200	250	-0.18	68	47	47	16
DTA144G	PNP	-50	-100	200	250	-1.8	68	0	47	K16
DTA144T	PNP	-50	-100	200	250	-0.88	100	47	∞	96
DTA144V	PNP	-50	-100	200	250	-0.18	33	47	10	56
DTA144W	PNP	-50	-100	200	250	-0.18	56	47	22	76
DTA214Y	PNP	-50	-100	200	250	-0.88	68	10	47	N14
DTA1D3R	PNP	-50	-100	200	250	-3.7	20	2.7	1	K38
DTB113E	PNP	-50	-500	200	250	-7.2	33	1	1	F11
DTB113Z	PNP	-50	-500	200	250	-7.2	56	1	10	G11
DTB114E	PNP	-50	-500	200	250	-0.88	56	10	10	F14
DTB114G	PNP	-50	-500	200	250	-7.2	56	0	10	L14
DTB114T	PNP	-50	-500	200	250	-0.88	100	10	∞	E94
DTB122J	PNP	-50	-500	200	250	-4.5	47	0.22	4.7	G3C
DTB123E	PNP	-50	-500	200	250	-3.8	39	2.2	2.2	F12
DTB123T	PNP	-50	-500	200	250	-7.2	100	2.2	∞	E92
DTB123Y	PNP	-50	-500	200	250	-3.6	56	2.2	10	F52



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		V	mA	mW	MHz	@V _{in} 5V	@5V50mA	KΩ	KΩ	
DTB13H	PNP	-50	-500	200	250	-2.4	56	3.3	10	G98
DTB143E	PNP	-50	-500	200	250	-1.8	47	4.7	4.7	F13
DTB143T	PNP	-50	-500	200	250	-0.88	100	4.7	∞	F03
DTB163T	PNP	-50	-500	200	250	-1.8	100	6.8	∞	E97
DTC113T	NPN	50	100	200	250	3.8	100	1	∞	1
DTC113Z	NPN	50	100	200	250	7.2	33	1	10	E12
DTC114E	NPN	50	100	200	250	0.88	30	10	10	24
DTC114G	NPN	50	100	200	250	7.2	30	0	10	K24
DTC114T	NPN	50	100	200	250	0.88	100	10	∞	4
DTC114W	NPN	50	100	200	250	0.88	24	10	4.7	84
DTC114Y	NPN	50	100	200	250	0.88	68	10	47	64
DTC115E	NPN	50	100	200	250	0.15	82	100	100	29
DTC115G	NPN	50	100	200	250	0.88	82	0	100	K29
DTC115T	NPN	50	100	200	250	0.15	100	100	∞	9
DTC115U	NPN	50	100	200	250	0.1	27	100	10	E89
DTC123E	NPN	50	100	200	250	3.8	20	2.2	2.2	22
DTC123J	NPN	50	100	200	250	3.8	80	2.2	47	E42
DTC123T	NPN	50	100	200	200	7.2	100	2.2	∞	N03
DTC123Y	NPN	50	100	200	250	3.8	33	2.2	10	62
DTC124E	NPN	50	100	200	250	0.38	56	22	22	25
DTC124G	NPN	50	100	200	250	0.88	56	0	22	K25
DTC124T	NPN	50	100	200	250	1.8	100	22	∞	5
DTC124X	NPN	50	100	200	250	0.38	68	22	47	45
DTC125T	NPN	50	100	200	250	0.33	100	200	∞	0A
DTC143E	NPN	50	100	200	250	1.8	20	4.7	4.7	23
DTC143T	NPN	50	100	200	250	7.2	100	4.7	∞	3
DTC143X	NPN	50	100	200	250	1.8	30	4.7	10	43
DTC143Y	NPN	50	100	200	250	1.8	56	4.7	22	63
DTC143Z	NPN	50	100	200	250	1.8	80	4.7	47	E23
DTC144E	NPN	50	100	200	250	0.18	68	47	47	26
DTC144G	NPN	50	100	200	250	1.8	68	0	47	K26
DTC144T	NPN	50	100	200	250	0.88	100	47	∞	6
DTC144V	NPN	50	100	200	250	0.18	33	47	10	E66
DTC144W	NPN	50	100	200	250	0.18	56	47	22	86
DTC214Y	NPN	50	100	200	250	0.88	68	10	47	N24
DTC1D3R	NPN	50	100	200	250	3.7	20	2.7	1	K4B
DTC314T	NPN	50	600	200	200	0.88	100	10	∞	H04
DTC323T	NPN	50	600	200	200	7.2	100	2.2	∞	H02
DTC343T	NPN	50	600	200	200	0.88	100	4.7	∞	H03
DTC363T	NPN	50	600	200	200	1.8	100	6.8	∞	H07
DTD113E	NPN	50	500	200	250	7.2	30	1	1	F21



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		V	mA	mW	MHz	@V _{in} 5V	@5V50mA	KΩ	KΩ	
DTD113Z	NPN	50	500	200	250	7.2	56	1	10	G21
DTD114E	NPN	50	500	200	250	0.88	56	10	10	F24
DTD114G	NPN	50	500	200	250	7.2	56	0	10	L24
DTD114T	NPN	50	500	200	250	0.88	100	10	∞	E04
DTD122J	NPN	50	500	200	250	4.5	47	0.22	4.7	G4C
DTD123E	NPN	50	500	200	250	3.8	39	2.2	2.2	F22
DTD123T	NPN	50	500	200	250	7.2	100	2.2	∞	E02
DTD123Y	NPN	50	500	200	250	3.8	56	2.2	10	F62
DTD133H	NPN	50	500	200	250	2.4	56	3.3	10	G06
DTD143E	NPN	50	500	200	250	1.8	47	4.7	4.7	F23
DTD143T	NPN	50	500	200	250	0.88	100	4.7	∞	F13
DTD163T	NPN	50	500	200	250	1.8	100	6.8	∞	E07
MUN2111	PNP	-50	-100	200	250	-0.88	30	10	10	6A
MUN2112	PNP	-50	-100	200	250	-0.38	56	22	22	6B
MUN2113	PNP	-50	-100	200	250	-0.18	68	47	47	6C
MUN2114	PNP	-50	-100	200	250	-0.88	68	10	47	6D
MUN2115	PNP	-50	-100	200	250	-0.88	100	10	∞	6E
MUN2116	PNP	-50	-100	200	250	-7.2	100	4.7	∞	6F
MUN2130	PNP	-50	-100	200	250	-4.3	3	1	1	6G
MUN2131	PNP	-50	-100	200	250	-2.3	8	2.2	2.2	6H
MUN2132	PNP	-50	-100	200	250	-1.5	15	4.7	4.7	6J
MUN2133	PNP	-50	-100	200	250	-0.18	80	4.7	47	6K
MUN2134	PNP	-50	-100	200	250	-0.13	80	22	47	6L
MUN2136	PNP	-50	-100	200	250	-0.15	82	100	100	6N
MUN2137	PNP	-50	-100	200	250	-0.18	56	47	22	6P
MUN2140	PNP	-50	-100	200	250	-0.88	100	47	∞	6T
MUN2211	NPN	50	100	200	250	0.5	35	10	10	8A
MUN2212	NPN	50	100	200	250	0.2	60	22	22	8B
MUN2213	NPN	50	100	200	250	0.1	80	47	47	8C
MUN2214	NPN	50	100	200	250	0.2	80	10	47	8D
MUN2215	NPN	50	100	200	250	0.9	160	10	∞	8E
MUN2216	NPN	50	100	200	250	1.9	160	4.7	∞	8F
MUN2230	NPN	50	100	200	250	4.3	5	1	1	8G
MUN2231	NPN	50	100	200	250	2.3	15	2.2	2.2	8H
MUN2232	NPN	50	100	200	250	1.5	30	4.7	4.7	8J
MUN2233	NPN	50	100	200	250	0.18	200	4.7	47	8K
MUN2234	NPN	50	100	200	250	0.13	150	22	47	8L
MUN2238	NPN	50	100	200	250	4	160	2.2	∞	8R
MUN2241	NPN	50	100	200	250	0.1	160	100	∞	8U
KRA101S	PNP	-50	-100	200	250	-1.8	30	4.7	4.7	PA
KRA102S	PNP	-50	-100	200	250	-0.88	30	10	10	PB



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產品型號 Type	極性 Polarity	V _{CC}	I _O	P _D	fT	I _I (mA)	G(min)	R1	R2	印字 Marking
		V	mA	mW	MHz	@V _{in} 5V	@5V5mA	KΩ	KΩ	
KRA103S	PNP	-50	-100	200	250	-0.38	56	22	22	PC
KRA104S	PNP	-50	-100	200	250	-0.18	68	47	47	PD
KRA105S	PNP	-50	-100	200	250	-3.6	80	2.2	47	PE
KRA106S	PNP	-50	-100	200	250	-1.8	80	4.7	47	PF
KRA107S	PNP	-50	-100	200	250	-0.88	68	10	47	PH
KRA108S	PNP	-50	-100	200	250	-0.36	68	22	47	PI
KRA109S	PNP	-50	-100	200	250	-0.18	56	47	22	PJ
KRA116S	PNP	-50	-100	200	250	-7.2	33	1	10	P2
KRA117S	PNP	-50	-100	200	250	-3.8	20	2.2	2.2	P4
KRA118S	PNP	-50	-100	200	250	-3.8	33	2.2	10	P5
KRA119S	PNP	-50	-100	200	250	-1.8	30	4.7	10	P6
KRA120S	PNP	-50	-100	200	250	-88	24	10	4.7	P7
KRA121S	PNP	-50	-100	200	250	-0.16	33	47	10	P8
KRA122S	PNP	-50	-100	200	250	-0.15	62	100	100	P9
KRA221S	PNP	-50	-500	200	250	-7.2	33	1	1	PQ
KRA222S	PNP	-50	-500	200	250	-3.8	39	2.2	2.2	PR
KRA223S	PNP	-50	-500	200	250	-1.8	47	4.7	4.7	PS
KRA224S	PNP	-50	-500	200	250	-0.88	56	10	10	PT
KRA225S	PNP	-50	-500	200	250	-7.2	56	1	10	PU
KRA226S	PNP	-50	-500	200	250	-3.6	56	2.2	10	PV
KRC101S	NPN	50	100	200	250	1.8	30	4.7	4.7	NA
KRC102S	NPN	50	100	200	250	0.88	50	10	10	NB
KRC103S	NPN	50	100	200	250	0.36	70	22	22	NC
KRC104S	NPN	50	100	200	250	0.18	80	47	47	ND
KRC105S	NPN	50	100	200	250	3.6	80	2.2	47	NE
KRC106S	NPN	50	100	200	250	1.8	80	4.7	47	NF
KRC107S	NPN	50	100	200	250	0.88	80	10	47	NH
KRC108S	NPN	50	100	200	250	0.36	80	22	47	NI
KRC109S	NPN	50	100	200	250	0.16	70	47	22	NJ
KRC116S	NPN	50	100	200	250	7.2	33	1	10	N2
KRC117S	NPN	50	100	200	250	3.8	20	2.2	2.2	N4
KRC118S	NPN	50	100	200	250	3.8	33	2.2	10	N5
KRC119S	NPN	50	100	200	250	1.8	30	4.7	10	N6
KRC120S	NPN	50	100	200	250	0.88	24	10	4.7	N7
KRC121S	NPN	50	100	200	250	0.16	33	47	10	N8
KRC122S	NPN	50	100	200	250	0.15	62	100	100	N9
KRC231S	NPN	50	600	200	250	-	200	2.2	∞	NW
KRC232S	NPN	50	600	200	250	-	200	5.6	∞	NY
KRC233S	NPN	50	600	200	250	-	200	10	∞	NZ
KRC234S	NPN	50	600	200	250	-	200	4.7	∞	NNA
KRC235S	NPN	50	600	200	250	-	200	6.8	∞	NNB